# **MA6X718** (MA718)

### Silicon epitaxial planar type

For switching

For wave detection

#### Features

- Three isolated elements are contained in one package, allowing high-density mounting
- Two MA3X704A (MA704A) is contained in one package (of a type in the same direction)
- Forward voltage V<sub>F</sub>, optimum for low voltage rectification
- Optimum for high frequency rectification because of its short reverse recovery time t<sub>rr</sub>

#### ■ Absolute Maximum Ratings T<sub>a</sub> = 25°C

Parameter	Symbol	Rating	Unit
Reverse voltage	$V_R$	30	V
Peak forward current *	$I_{FM}$	150	mA
Forward current *	$I_{\mathrm{F}}$	30	mA
Junction temperature	Tj	125	°C
Storage temperature	T <sub>stg</sub>	-55 to +125	S°C .

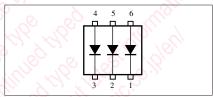
Note) \*: Value for single diode

### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

2.90 <sup>+0.20</sup> 1.99.1 1.99.1 (0.95), (0.95) 4 5 6 1 0.30 <sup>+0.10</sup> 0.50 <sup>+0.10</sup> 0.50 <sup>+0.10</sup> 10	(0.65) 1.50 <sup>+0.25</sup> 2.8 <sup>+0.2</sup>	Unit: mm  0.16 <sup>+0.10</sup> -0.06
	0 to 0.1 1.1 <sup>+0.2</sup>	1 : Cathode 1 2 : Cathode 2 3 : Cathode 3 4 : Anode 3 5 : Anode 2
EIAJ : SC-74		6 : Anode 1 Mini6-G1 Package

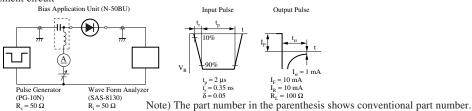
Marking Symbol: M2N

#### Internal Connection

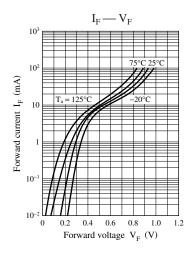


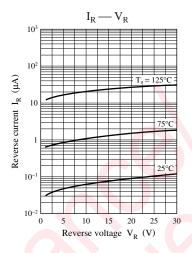
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{F1}$	$I_F = 1 \text{ mA}$		)-	0.4	V
	$V_{F2}$	$I_F = 30 \text{ mA}$	1.90		1.0	
Reverse current	$I_R$	$V_R = 30 \text{ V}$			1	μΑ
Terminal capacitance	C <sub>t</sub>	$V_R = 1 \text{ V, f} = 1 \text{ MHz}$		1.5		pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 10 \text{ mA}$		1.0		ns
		$I_{rr} = 1 \text{ mA}$ , $R_L = 100 \Omega$				
Detection efficiency	η	$V_{IN} = 3 V_{(peak)}$ , $f = 30 MHz$		65		%
H.		$R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$				

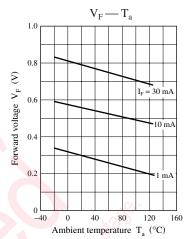
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 2 GHz.
  - 4. \*: t<sub>rr</sub> measurement circuit

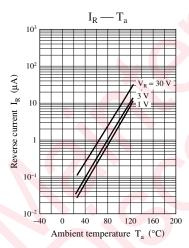


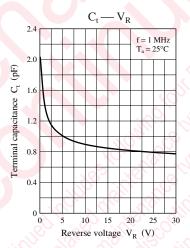
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2

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